ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND	
VCC, A, B, C, and ENABLE	0.3V to +4.6V
Voltage at Any Other Terminal	
(Note 1)	-0.3V to (V _{CC} + 0.3V)
Continuous Current into A, B, C, ENABLE.	±10mA
Continuous Current into X, Y, Z, X_, Y_, Z_	±150mA
Peak Current into X, Y, Z, X_, Y_, Z_	
(pulsed at 1ms, 10% duty cycle)	±300mA

Continuous Power Dissipation

16-Pin Thin QFN (derate 16.9mW/°C about 16-Pin TSSOP (derate 5.7mW/°C above	
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

M/IXI/M

Note 1: Signals on X, Y, Z, X_, Y_, and Z_ exceeding V_{CC} or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V_{CC} = +2.7V to +3.6V, GND = 0, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	МАХ	UNITS
ANALOG SWITCH							
Analog Signal Range	V _X , V _Y , V _Z , V _X _, V _Y _, V _Z _			0		Vcc	V
On-Resistance (Note 4)	R _{ON}	V _{CC} = +2.7V; I _X _, I _Y _, I _Z = 100mA; V _X , V _Y , V _Z = 1.7V	+25°C T _{MIN} to T _{MAX}		0.7	1 1.2	Ω
On-Resistance Match Between Channels	ΔR _{ON}	V _{CC} = +2.7V; _{X_} , _{Y_} , _{Z_} =	+25°C		0.3	0.4	Ω
(Notes 4, 5)		100mA; V _X , V _Y , V _Z = 1.7V	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			0.6	
On-Resistance Flatness	R _{FLAT(ON)}	V _{CC} = +2.7V; I _X _, I _Y _, I _Z _ = 100mA; V _X , V _Y , V _Z = 0, 0.7V,	+25°C		0.1	0.2	Ω
(Note 6)	TFLAT(UN)	1.7V $1.7V$	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			0.2	
X_, Y_, Z_	IX_(OFF) IY_(OFF) IZ_(OFF)	$\begin{array}{l} V_{CC} = +3.6V; \\ V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 3.3V, \ 0.3V; \ V_{X}, \\ V_{Y}, V_{Z} = 0.3V, \ 3.3V \end{array}$	+25°C	-2	0.002	+2	nA
Off-Leakage Current			$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-7		+7	
X Off-Leakage Current	IX(OFF)	V _{CC} = +3.6V; V _X = 3.3V, 0.3V; V _X = 0.3V, 3.3V	+25°C	-2	0.002	+2	nA
(MAX4781 Only)			$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-50		+50	177
X On-Leakage Current	IX(ON)	$V_{CC} = +3.6V$ $V_X = 0.3V, 3.3V;$	+25°C	-2	0.002	+2	nA
(MAX4781 Only)	IX(ON)	$V_{X_{-}} = 0.3V, 3.3V$ or floating	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-50		+50	11/ (
X, Y, Z Off-Leakage Current	IX(OFF) IY(OFF) IZ(OFF)	V _{CC} = +3.6V; V _X _, V _Y _, V _Z _ = 3.3V, 0.3V; V _X , V _Y , V _Z = 0.3V, 3.3V	+25°C	-2	0.002	+2	
(MAX4782/MAX4783 Only)			$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	-25		+25	nA
X, Y, Z On-Leakage Current	IX(ON)	V _{CC} = +3.6V;	+25°C	-2	0.002	+2	
(MAX4782/MAX4783 Only)	ly(ON) lz(ON)	V_X , V_Y , $V_Z = 0.3V$, 3.3V; V_X , V_Y , $V_Z = 0.3V$, 3.3V or floating	T _{MIN} to T _{MAX}	-25		+25	nA

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ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V_{CC} = +2.7V \text{ to } +3.6V, \text{GND} = 0, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} \text{ to } T_{MAX}$, unless otherwise noted. Typical values are at $T_A = +25^{\circ}$ C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDIT	ONS	TA	MIN	ТҮР	MAX	UNITS
SWITCH DYNAMIC CHARACT	ERISTICS			1				
T 0 T		·, ·, · ·, · · · · · · · · · · · · · ·		+25°C		11	25	
Turn-On Time	ton			T _{MIN} to T _{MAX}			27	ns
Turn-Off Time	torr	toff (,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		+25°C		4	15	20
Tum-Oli Time	LOFF			$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$		20		ns
Address Transition Time	t TRANS	$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.5V; R_{L} = 50\Omega; +$		+25°C		11	25	25 ns
	U RANS	$C_L = 35 pF;$ Figure	e 2	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			27	115
Break-Before-Make Time	tBBM	$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.5$		+25°C		18		ns
(Note 7)	UDIVI	$C_L = 35 pF;$ Figure	e 3	$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	2			110
Charge Injection	Q	V _{GEN} = 0, R _{GEN} = Figure 4	0, C _L = 1nF,	+25°C		-110		рС
Input Off-Capacitance	CX_(OFF), C _{Y_} (OFF), CZ_(OFF)	f = 1MHz, Figure 6		+25°C	38		pF	
	Cx(OFF), Cy(OFF), Cz(OFF)	f = 1MHz, Figure 6	MAX4781			310		pF
Output Off-Capacitance			MAX4782	+25°C	158			
			MAX4783		75			
	C _{X(ON)} C _{Y(ON)}	f = 1MHz, Figure 6	MAX4781			380		рF
Output On-Capacitance			MAX4782	+25°C	224			
	C _{Z(ON)}	i iguie e	MAX4783	140				
Off-Isolation (Note 8)	VISO	$R_L = 50\Omega$, $C_L =$	f = 10MHz			-75		dB
	130	35pF, Figure 5	f = 1MHz			-90		GD
Channel-to-Channel Crosstalk	VCT	$R_L = 50\Omega$, $C_L =$	f = 10MHz	_		-65		dB
(Note 9)		35pF, Figure 5	f = 1MHz			-80		GD
Total Harmonic Distortion	THD	f = 20Hz to $20kH$	z, 0.5V _{P-P} , R _L	= 32Ω		0.045		%
DIGITAL I/O				1	1			
Input Logic High	VIH			$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$	1.4			V
Input Logic Low	VIL			$T_{\mbox{MIN}}$ to $T_{\mbox{MAX}}$			0.5	V
Input Leakage Current	I _{IN} _	V_A , V_B , $V_C = V_{\overline{ENABLE}} = 0$ or 3.6V		T_{MIN} to T_{MAX}	-1	0.0005	+1	μA
POWER SUPPLY								
Power-Supply Range	V _{CC}				+1.6		+3.6	V
Positive Supply Current	Icc	$V_{CC} = 3.6V; V_A, V_B, V_C;$ $V_{ENABLE} = 3.6V \text{ or } 0$					1	μA



ELECTRICAL CHARACTERISTICS—Single +1.8V Supply

(V_{CC} = +1.8V, GND = 0, V_{IH} = 1V, V_{IL} = 0.4V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

						, (
PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS
ANALOG SWITCH	•	•					
Analog Signal Range	Vx_, Vy_, Vz_, Vx, Vy, Vz			0		V _{CC}	V
On-Resistance (Note 4)	R _{ON}	V _{CC} = 1.8V; I _X , I _Y , I _Z = 10mA; V _X , V _Y , V _Z = 1.0V	+25°C T _{MIN} to T _{MAX}		1.6	2.5 3.5	Ω
On-Resistance Match Between Channels (Notes 4, 5)	ΔR _{ON}	$V_{CC} = 1.8V; I_X, I_Y, I_Z = 10mA;$ $V_X, V_Y, V_Z = 1.0V$	+25°C T _{MIN} to T _{MAX}		0.3	0.4 0.6	Ω
SWITCH DYNAMIC CHARACTE	RISTICS						
Turn-On Time	ton	$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.0V; R_{L} = 50\Omega;$	+25°C		17	30	ns
		$C_L = 35 pF;$ Figure 1	T _{MIN} to T _{MAX}			32	
Turn-Off Time	tOFF	$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.0V; R_{L} = 50\Omega;$ $C_{L} = 35pF;$ Figure 1	+25°C T _{MIN} to T _{MAX}		8	20 22	ns
Address Transition Time	t _{TRANS}	$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1.0V; R_{L} = 50\Omega;$ $C_{L} = 35pF;$ Figure 2	+25°C		17	30 32	ns
Break-Before-Make Time (Note 7)	tBBM	$V_{X_{-}}, V_{Y_{-}}, V_{Z_{-}} = 1V; R_{L} = 50\Omega;$ $C_{L} = 35pF; Figure 3$	+25°C T _{MIN} to T _{MAX}	1	26		ns
Charge Injection	Q	$V_{\text{GEN}} = 0, R_{\text{GEN}} = 0, C_{\text{L}} = 1 \text{nF},$ Figure 4	+25°C		-40		рС
DIGITAL I/O							•
Input Logic High	VIH		T _{MIN} to T _{MAX}	1			V
Input Logic Low	VIL		T _{MIN} to T _{MAX}			0.4	V
Input Leakage Current	I _{IN} _	V_A , V_B , $V_C = V_{\overline{\text{ENABLE}}} = 0 \text{ or } 3.6V$	T _{MIN} to T _{MAX}	-1	0.000	+1	μA
POWER SUPPLY							
Power-Supply Range	V _{CC}			1.6		3.6	V
Positive Supply Current	ICC	$V_{CC} = 3.6V$; V_A , V_B , V_C , $V_{\overline{ENABLE}} = 0 \text{ or } 3.6V$				1	μA

Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 3: Devices are tested at maximum hot temperature and are guaranteed by design and correlation at $T_A = +25^{\circ}C$ and $-40^{\circ}C$ specifications.

Note 4: R_{ON} and ΔR_{ON} matching specifications for thin QFN-packaged parts are guaranteed by design.

Note 5: $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$.

Note 6: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

M/IXI/N

Note 7: Guaranteed by design; not production tested.

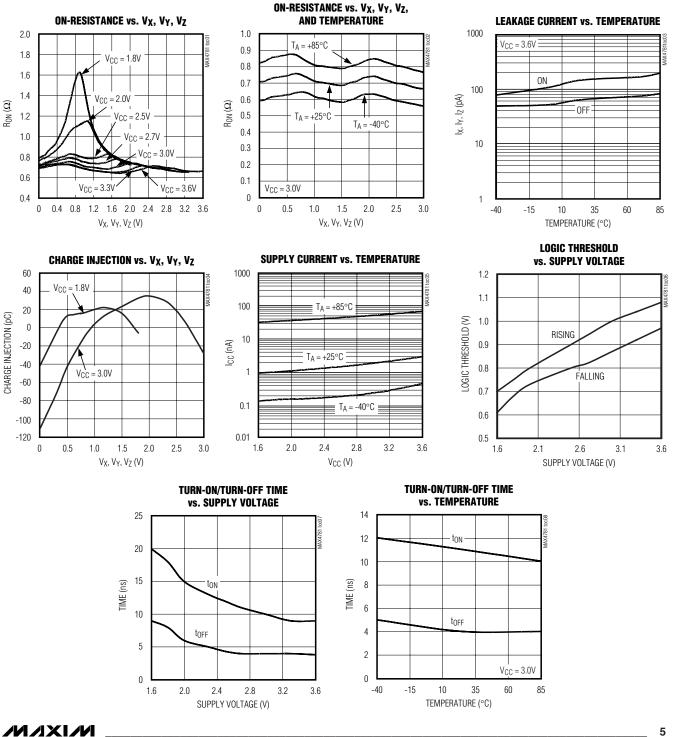
Note 8: Off-isolation = $20\log 10(V_{COM_} / V_{NO})$, $V_{COM_}$ = output, V_{NO} = input to off switch.

Note 9: Between any two channels.

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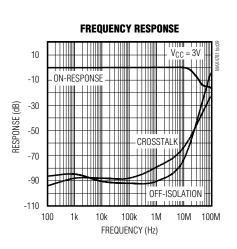
Typical Operating Characteristics

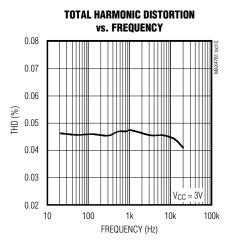
 $(GND = 0, T_A = +25^{\circ}C, unless otherwise noted.)$



_Typical Operating Characteristics (continued)

(GND = 0, T_A = +25°C, unless otherwise noted.)





MAX4781 Pin Description

PIN		NAME	FUNCTION		
TSSOP	THIN QFN	NAME	FUNCTION		
3	1	Х	Analog Switch Output		
6	4	ENABLE	Digital Enable Input. Normally connect to GND. Drive to logic high to set all switches off.		
7	5	N.C.	No Connection. Not internally connected.		
8	6	GND	Ground		
9	7	С	Digital Address C Input		
10	8	В	Digital Address B Input		
11	9	А	Digital Address A Input		
13, 14, 15, 12, 1, 5, 2, 4	11, 12, 13, 10, 15, 3, 16, 2	X0–X7	Analog Switch Inputs X0–X7		
16	14	V _{CC}	Positive Analog and Digital Supply Voltage Input		
	EP	PAD	Exposed Pad. Connect to GND.		

MAX4782 Pin Description

P	IN	NAME	FUNCTION	
TSSOP	THIN QFN	NAME	FUNCTION	
1, 5, 2, 4	15, 3, 16, 2	Y0–Y3	Analog Switch Y Inputs Y0–Y3	
3	1	Y	Analog Switch Y Output	
6	4	ENABLE	Digital Enable Input. Normally connect to GND. Drive to logic high to set all switches off.	
7	5	N.C.	No Connection. Not internally connected.	
8	6	GND	Ground	
9	7	В	Digital Address B Input	
10	8	А	Digital Address A Input	
12, 14, 15, 11	10, 12, 13, 9	X0–X3	Analog Switch X Inputs X0–X3	
13	11	Х	Analog Switch X Output	
16	14	V _{CC}	Positive Analog and Digital Supply Voltage Input	

MAX4783 Pin Description

Р	IN	NAME	FUNCTION	
TSSOP	THIN QFN	NAME	FUNCTION	
1	15	Y1	Analog Switch Y Normally Open Input	
2	16	YO	Analog Switch Y Normally Closed Input	
3	1	Z1	Analog Switch Z Normally Open Input	
4	2	Z	Analog Switch Z Output	
5	3	ZO	Analog Switch Z Normally Closed Input	
6	4	ENABLE	Digital Enable Input. Normally connect to GND. Drive to logic high to set al switches off.	
7	5	N.C.	No Connection. Not internally connected.	
8	6	GND	Ground	
9	7	С	Digital Address C Input	
10	8	В	Digital Address B Input	
11	9	А	Digital Address A Input	
12	10	XO	Analog Switch X Normally Closed Input	
13	11	X1	Analog Switch X Normally Open Input	
14	12	Х	Analog Switch X Output	
15	13	Y	Analog Switch Y Output	
16	14	V _{CC}	Positive Analog and Digital Supply Voltage Input	

MAX4781/MAX4782/MAX4783

High-Speed, Low-Voltage, 0.7 Ω CMOS Analog Switches/Multiplexers

Applications Information

Power-Supply Considerations

Overview

The MAX4781/MAX4782/MAX4783 construction is typical of most CMOS analog switches. There are two supply inputs: V_{CC} and GND. V_{CC} and GND drive the internal CMOS switches and set the limits of the analog voltage on any switch. Internal reverse ESD-protection diodes are connected between each analog signal input and both V_{CC} and GND. If any analog signal exceeds V_{CC} or GND, one of these diodes conducts. During normal operation, these and other reverse-biased ESD diodes leak, forming the only current drawn from V_{CC} or GND.

Virtually all the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal input are identical and therefore fairly well balanced, they are reverse-biased differently. Each diode is biased by either V_{CC} or GND and the analog signal. Their leakages vary as the signal varies. The difference in the two diodes' leakages to V_{CC} and GND constitutes the analog-signal-path leakage current. All analog leakage current flows between each input and one of the supply terminals, not to the other switch terminal. Both sides of a given switch can show leakage currents of either the same or opposite polarity.

V_{CC} and GND power the internal logic and set the input logic limits. Logic inputs have ESD-protection diodes to ground.

Power Supply The MAX4781/MAX4782/MAX4783 operate from a single supply between +1.6V and +3.6V. Switch on-resistance increases as the supply voltage is lowered.

High-Frequency Performance

In 50 Ω systems, signal response is reasonably flat up to 50MHz (see the *Typical Operating Characteristics*). Above 20MHz, the on-response has several minor peaks that are highly layout dependent. In the off state, the switch acts like a capacitor and passes higher frequencies with less attenuation. At 10MHz, off-isolation is approximately -50dB in 50 Ω systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedance also degrades off-isolation. Adjacent channel attenuation is approximately 3dB above that of a bare IC socket and is entirely because of capacitive coupling.

Pin Nomenclature

The MAX4781/MAX4782/MAX4783 are pin compatible with the industry-standard 74HC4051/74HC4052/ 74HC4053 and the MAX4617/MAX4618/MAX4619. In single-supply applications, they function identically and have identical logic diagrams, although these parts differ electrically. The pin designations and logic diagrams in this data sheet conform to the original 1972 specifications published by RCA for the CD4051/ CD4052/CD4053. These designations differ from the standard Maxim switch and mux designations found on other Maxim data sheets such as the MAX4051/ MAX4052/MAX4053. Designers who are more comfortable with Maxim's standard designations are advised that the pin designations and logic diagrams on the MAX4051/MAX4052/MAX4053 data sheet can be applied to the MAX4781/MAX4782/MAX4783.

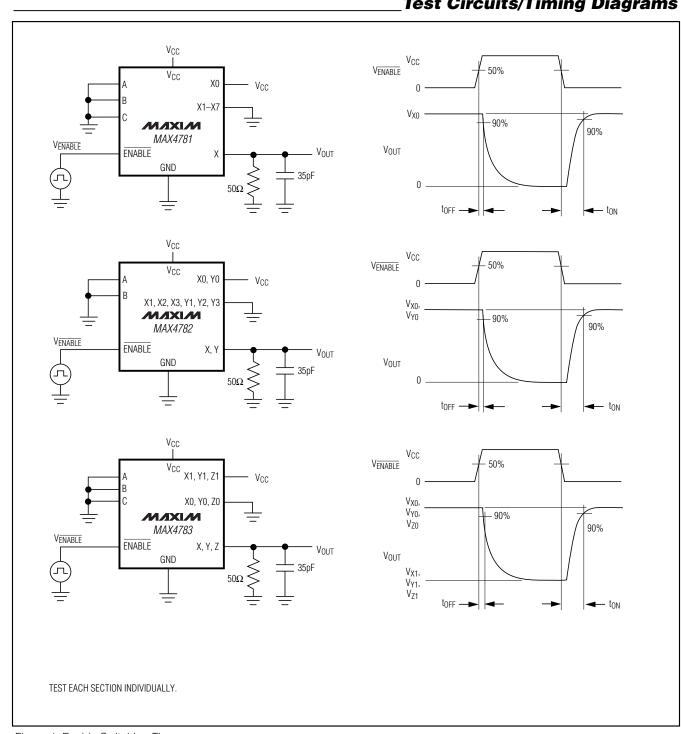
ENABLE		SELECT INPUT		ON SWITCHES			
INPUT	C*	В	Α	MAX4781	MAX4782	MAX4783	
Н	1	1	1	All switches open	All switches open	All switches open	
L	L	L	L	X-X0	X-X0 Y-Y0	X-X0 Y-Y0 Z-Z0	
L	L	L	Н	X-X1	X-X1 Y-Y1	X-X1 Y-Y0 Z-Z0	
L	L	Н	L	X-X2	X-X2 Y-Y2	X-X0 Y-Y1 Z-Z0	
L	L	Н	н	X-X3	X-X3 Y-Y3	X-X1 Y-Y1 Z-Z0	
L	Н	L	L	X-X4	X-X0 Y-Y0	X-X0 Y-Y0 Z-Z1	
L	Н	L	н	X-X5	X-X1 Y-Y1	X-X1 Y-Y0 Z-Z1	
L	Н	Н	L	X-X6	X-X2 Y-Y2	X-X0 Y-Y1 Z-Z1	
L	н	Н	н	X-X7	X-X3 Y-Y3	X-X1 Y-Y1 Z-Z1	

Table 1. Truth Table/Switch Programming

✓ = Don't care.

*Not present on MAX4782.

Note: Input and output pins are identical and interchangeable. Either can be considered an input or output. Signals pass equally well in either direction.

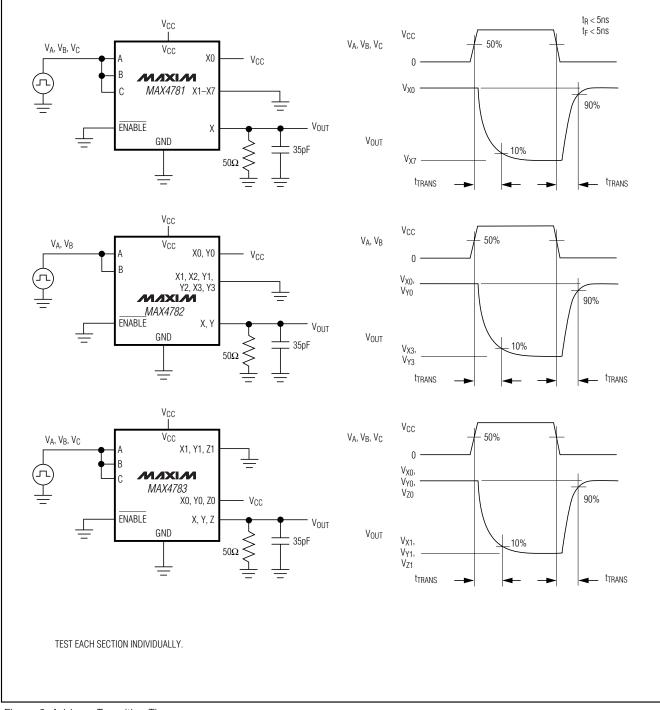


Test Circuits/Timing Diagrams

M/IXI/N

Figure 1. Enable Switching Times

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Test Circuits/Timing Diagrams (continued)

Figure 2. Address Transition Times

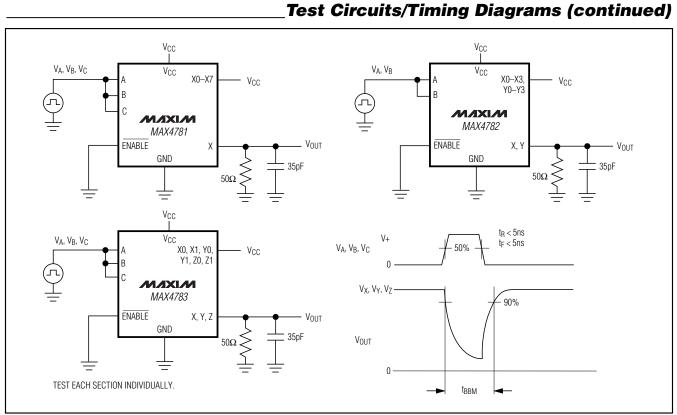


Figure 3. Break-Before-Make Interval

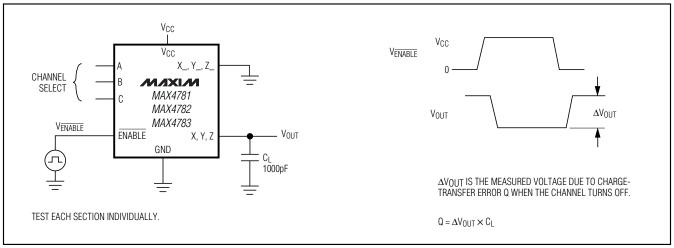
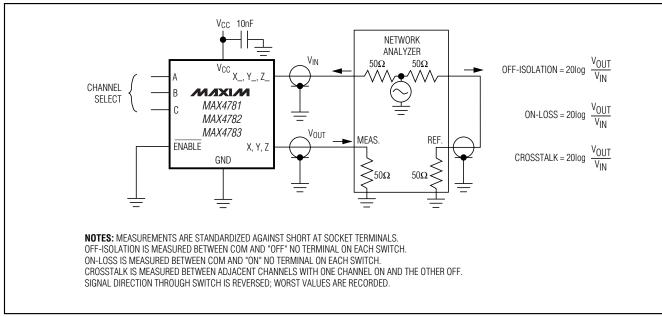


Figure 4. Charge Injection



_Test Circuits/Timing Diagrams (continued)

Figure 5. Off-Isolation, On-Loss, and Crosstalk

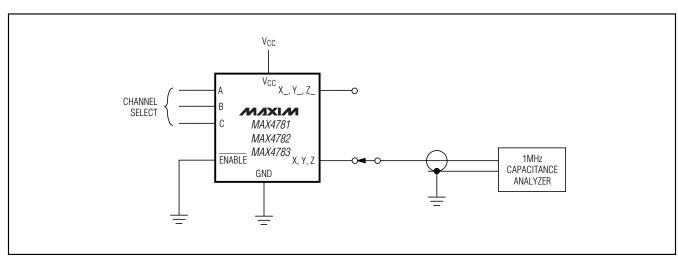
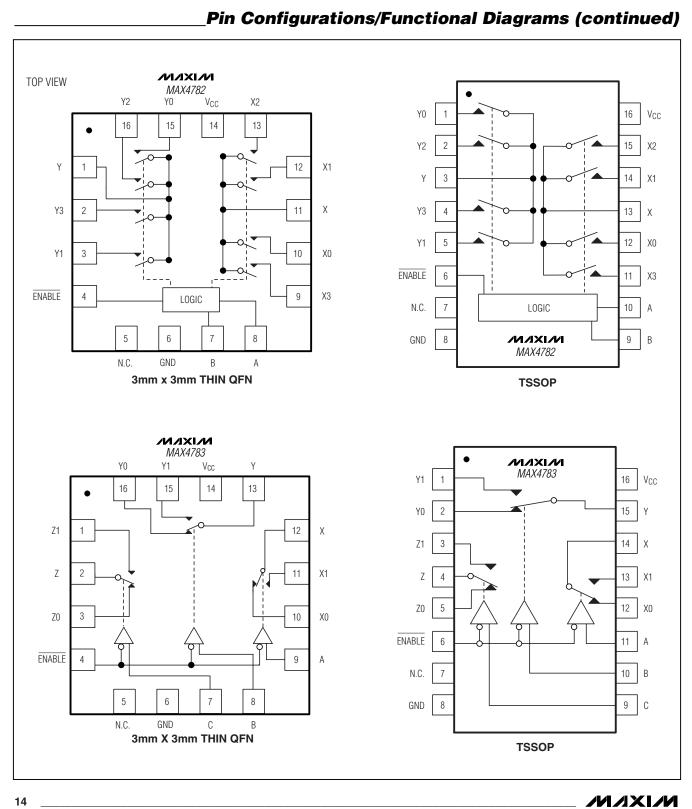


Figure 6. Capacitance

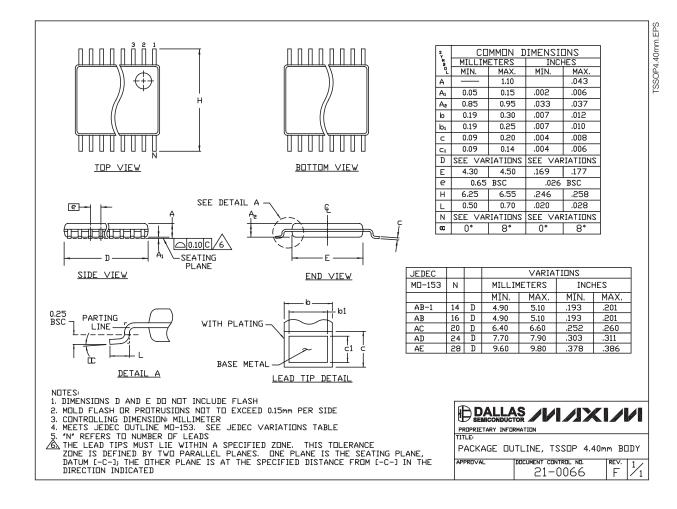
_Chip Information

TRANSISTOR COUNT: 659 PROCESS: CMOS



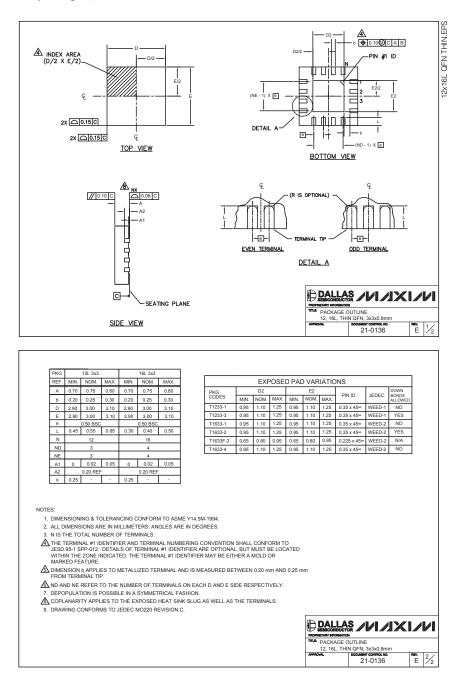
Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



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